E4D10120A

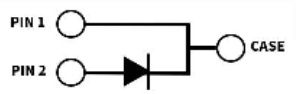
E-Series Automotive
4th Generation 1200 V, 10 A Silicon Carbide Schottky Diode

Description

With the performance advantages of a Silicon Carbide (SiC) Schottky Barrier diode, power electronics systems can expect to meet higher e iciency standards than Si-based solutions, while also reaching higher frequencies and power densities. SiC diodes can be easily paralleled to meet various application demands, without concern of thermal runaway. In combination with the reduced cooling requirements and improved thermal performance of SiC products, SiC diodes are able to provide lower overall system costs in a variety of diverse applications.

RoHS COMPLIANT

Halogen-Free



Package Types: TO-220-2
Marking: E4D10120A

Features

- Low Forward Voltage (V_F) Drop with Positive Temperature Coe icient
- Zero Reverse Recovery Current / Forward Recovery Voltage
- Temperature-Independent Switching Behavior
- Automotive Qualified (AEC Q101) and PPAP Capable

Applications

- Industrial Switched Mode Power Supplies
- Uninterruptible & AUX Power Supplies
- Boost for PFC & DC-DC Stages
- Solar Inverters

Maximum Ratings (T_C = 25°C Unless Otherwise Specified)

Parameter	Symbol	Value	Unit	Test Conditions	Notes
Repetitive Peak Reverse Voltage	V_{RRM}	1200	V		
DC Blocking Voltage	V_{DC}	1200			
Continuous Forward Current	I_F	33	A	T_J = 25 °C	Fig. 3
		16		T_J = 135 °C	
		10		T_J = 156 °C	
Repetitive Peak Forward Surge Current	I_{FRM}	44		T_C = 25 °C, t_p = 10 ms, Half Sine Wave	
		26		T_C = 110 °C, t_p = 10 ms, Half Sine Wave	
Power Dissipation	P_{tot}	166	W	T_J = 25 °C	Fig. 4
		72		T_J = 110 °C	
Diode dV/dt ruggedness	dV/dt	250	V/ns	V_R = 0-960V	

4600 Silicon Drive | Durham, NC 27703 | Tel: +1.919.313.5300 | wolfspeed.com/power

Electrical Characteristics

Parameter	Symbol	Typ.	Max.	Unit	Test Conditions	Notes
Forward Voltage	V_F	1.5	1.8	V	I_F = 10 A, T_j = 25 °C	Fig. 1
		2.2			I_F = 10 A, T_j = 175 °C	
Reverse Current	I_R	30	200	µA	V_R = 1200 V, T_j = 25 °C	Fig. 2
		55			V_R = 1200 V, T_j = 175 °C	
Total Capacitive Charge	Q_C	56		nC	V_R = 800 V, T_j = 25 °C	Fig. 5
Total Capacitance	C	77		pF	V_R = 0 V, T_j = 25 °C, f = 1 MHz	Fig. 6
		51				

Typical Performance

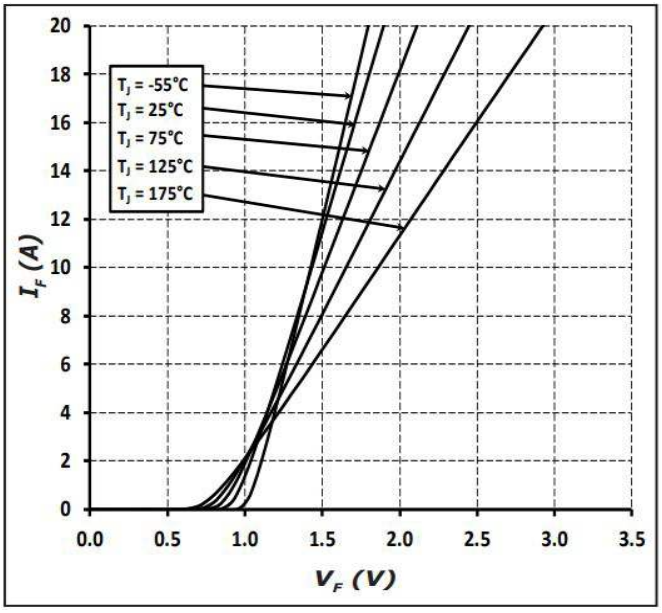


Figure 1
Forward Characteristics

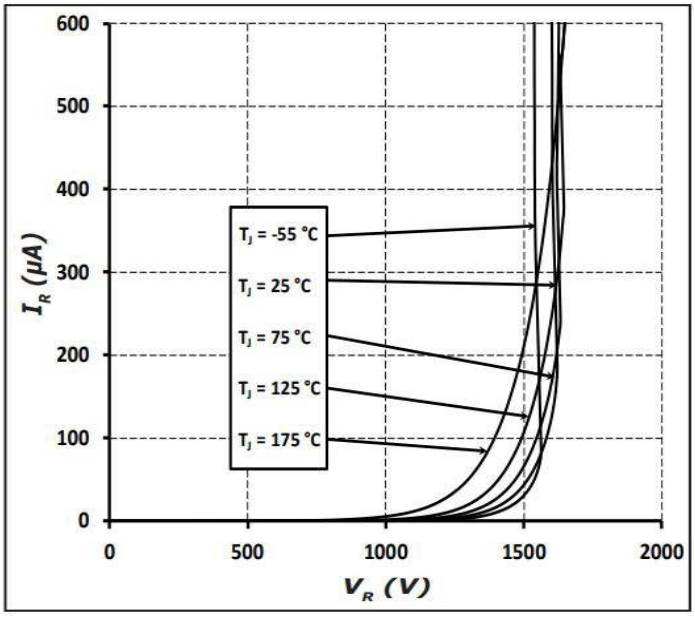


Figure 2
Reverse Characteristics

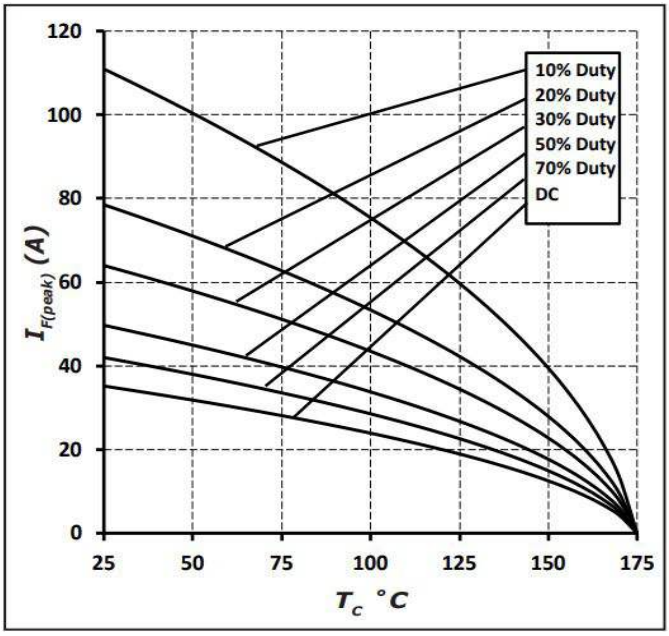


Figure 3
Current Derating

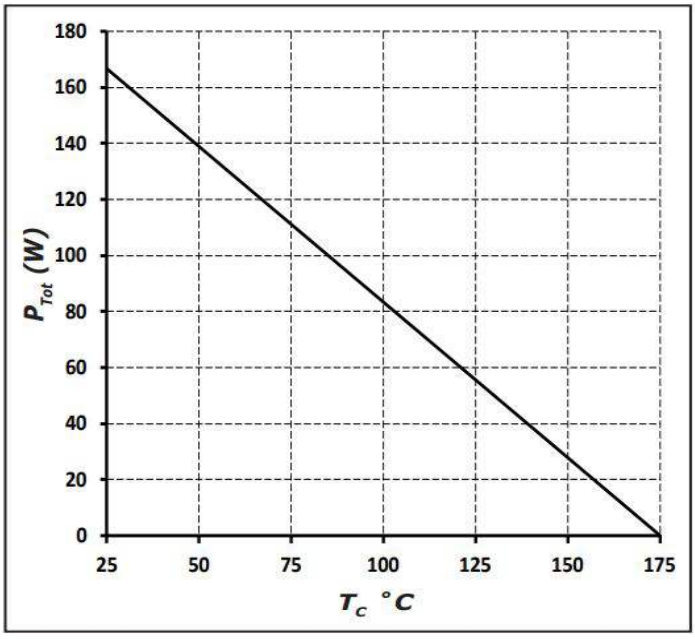


Figure 4
Power Derating

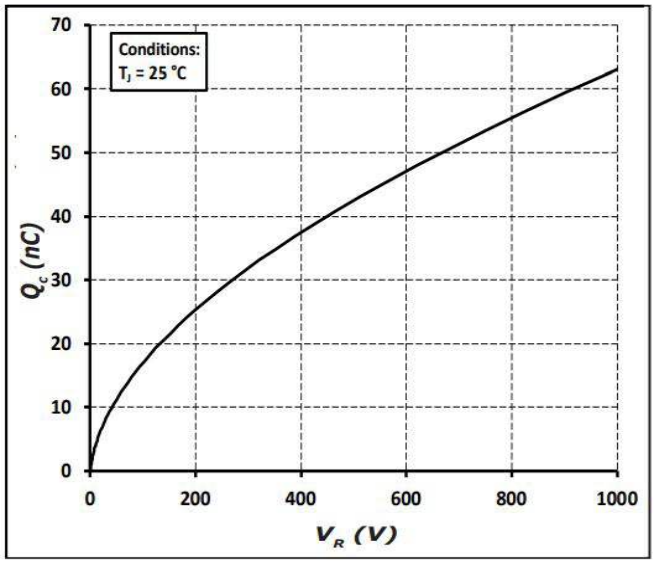


Figure 5
Total Capacitance vs. Reverse Voltage

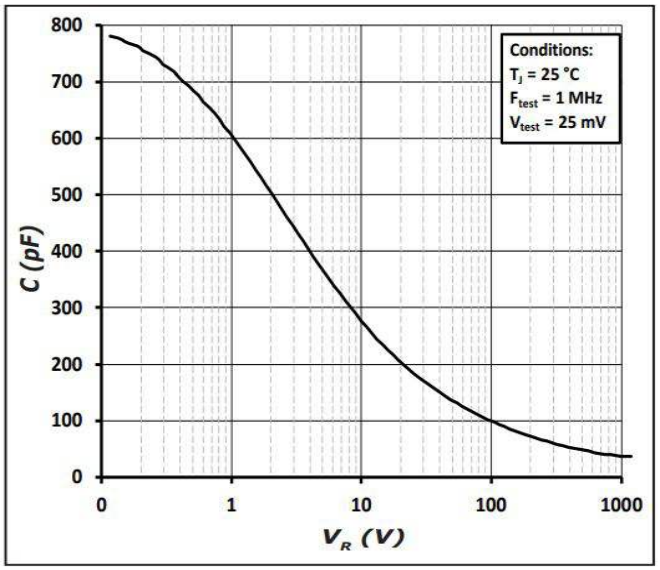


Figure 6
Capacitace vs. Reverse Voltage

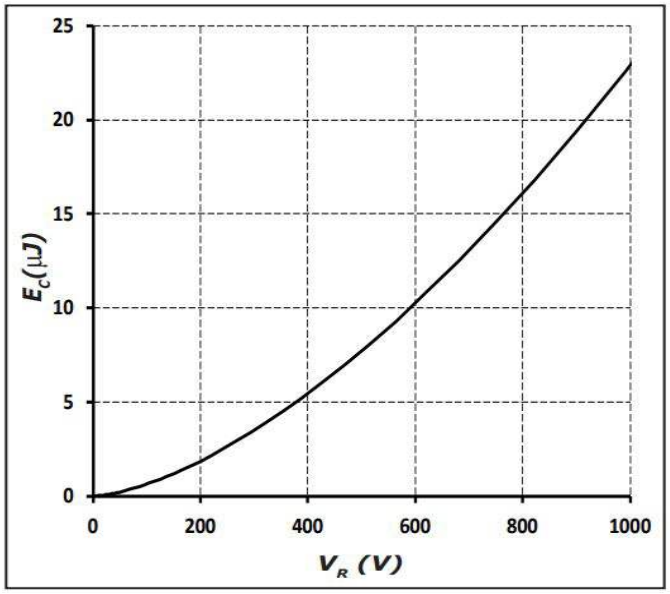


Figure 7
Capacitance Stored Energy

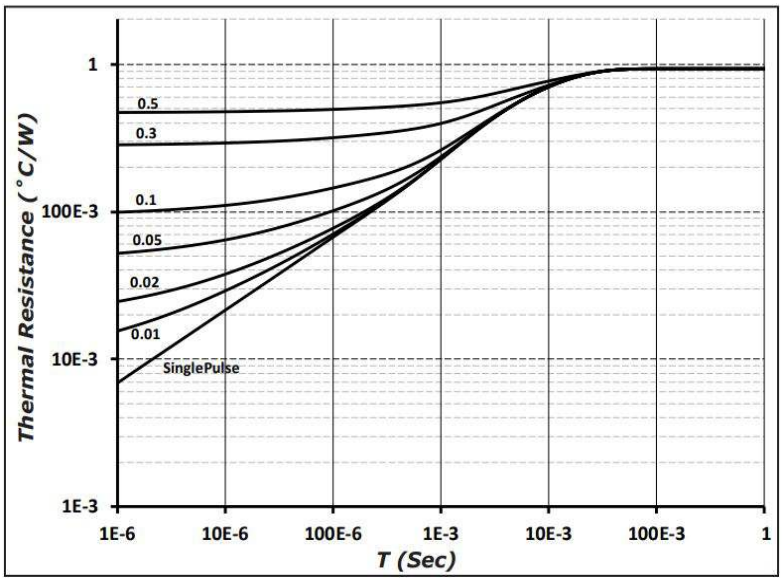
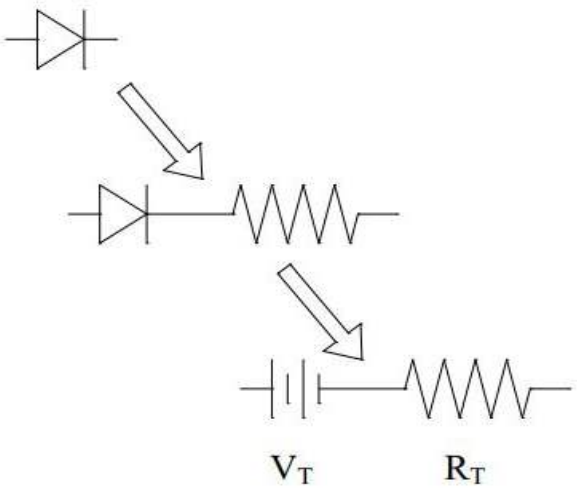


Figure 9
Transient Thermal Impedance

Diode Model



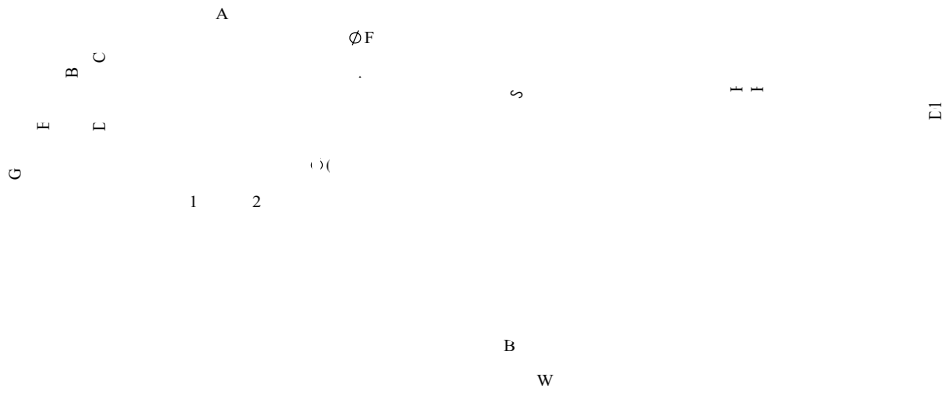
$$V_{fT} = V_T + If * R_T$$

$$V_T = 1.00 + (T_J * -1.10*10^{-3})$$
$$R_T = 0.03 + (T_J * 4.00*10^{-4})$$

Note: T_J = Diode Junction Temperature In Degrees Celsius, valid from 25°C to 175°C

Package Dimensions & Pin-Out

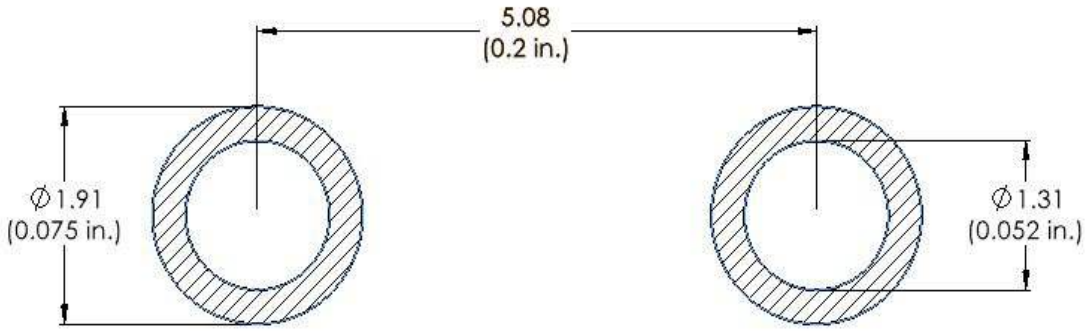
Package: TO-220-2



NOTE
1. ALL METAL SURFACES ARE TIN PLATED (MATTE), EXCEPT AREA OF CUT.
2. DIMENSIONING & TOLERANCING CONFORM TO ASME Y14.5M-1994.
3. ALL DIMENSIONS ARE LISTED IN MILLIMETERS. ANGLES ARE IN DEGREES.
4. PACKAGE BURR FLASH SIZE (0.5 mm) IS NOT INCLUDED IN THE DIMENSIONS

Recommended Solder Pad Layout

Primary dimensions shown in mm.



Product Ordering Information

Order Number	Packing Type
E4D10120A	Tube

Revision History

Document Version	Date of Release	Description of Changes
0	July-2016	Initial Release
1	March-2023	Update Package Drawing Update Landing Pad

Notes & Disclaimer

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Contact info:

4600 Silicon Drive
Durham, NC 27703 USA
Tel: +1.919.313.5300
www.wolfspeed.com/power